

## Status of SiPM Developments

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On behalf of **MEPhI-MPI for Physics-Pulsar** Collaboration(MMP)

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SiPM today:

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High gain,good S/N ratio  
Good single electron resolution  
Very good timing  
Small recovery time  
Very low nuclear counting effect  
Insensitivity to B  
Simple calibration and monitoring  
Vow bias voltage  
Low power consumption  
Compactness  
Room temperature operation  
Good T and V stability  
Not damaged even by ambient light  
Relatively low expected cost(low resistivity Si,simple technology)

Not very high PDE

Small area

High dark rate(~ area)

Excess Noise Factor is  
Large enough due to  
Optical Xtalk

Afterpulses

## Optical crosstalk OC

One phe gives rise more than one pixel fired due to secondary photons  
~  $3 \times 10^5$  photons (~1000nm) per one electron in Geiger discharge

### OC

- does not depend on temperature
- proportional to  
Gain x Photon Detection Efficiency

The larger PDE  
→ the larger pixel size  
→ The larger Gain

## Afterpulsing AP

Capture of avalanche electron by traps and its delayed release giving the secondary Geiger discharge in the same pixel

### AP

- proportional to  
Gain x PDE
- increases for low temperature the same recovery time because trap lifetime increase

# Optical Crosstalk and Afterpulsing

→ Give rise the non-Poisson statistics of fired pixels (SiPM response).

→ As a result:

→ SiPM pulse hight resolution is worsening:

→  $(\sigma/A)^2 > 1/N$  phe

Excess Noise Factor ENF  $> 1$

→ Sci Spectrometry(PET etc.) ?

ENF: for PMT  $\sim 1.2$

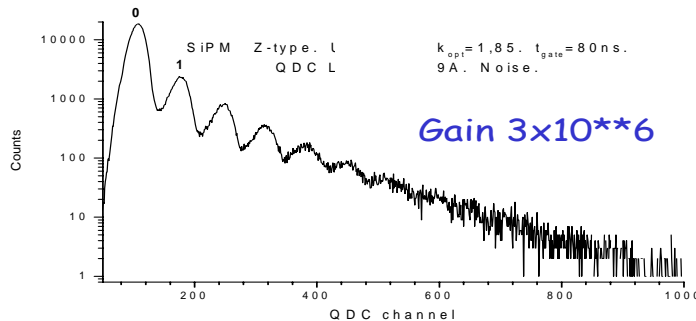
for APD  $\sim 2-2.5$

for SiPM(desirable)  $< 1.05$

# Optical Crosstalk and Afterpulsing

→ Long tail in SiPM pulse height distribution vs threshold

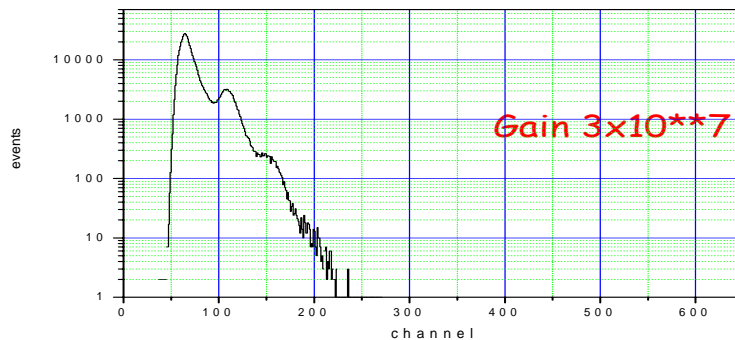
Optical crosstalk, SiPM 1x1 mm<sup>2</sup>, dark noise



Crosstalk → non-Poissonian distribution:

pixel fired/phe=1.7

ENF=1.6



Crosstalk suppression by special SiPM topology:

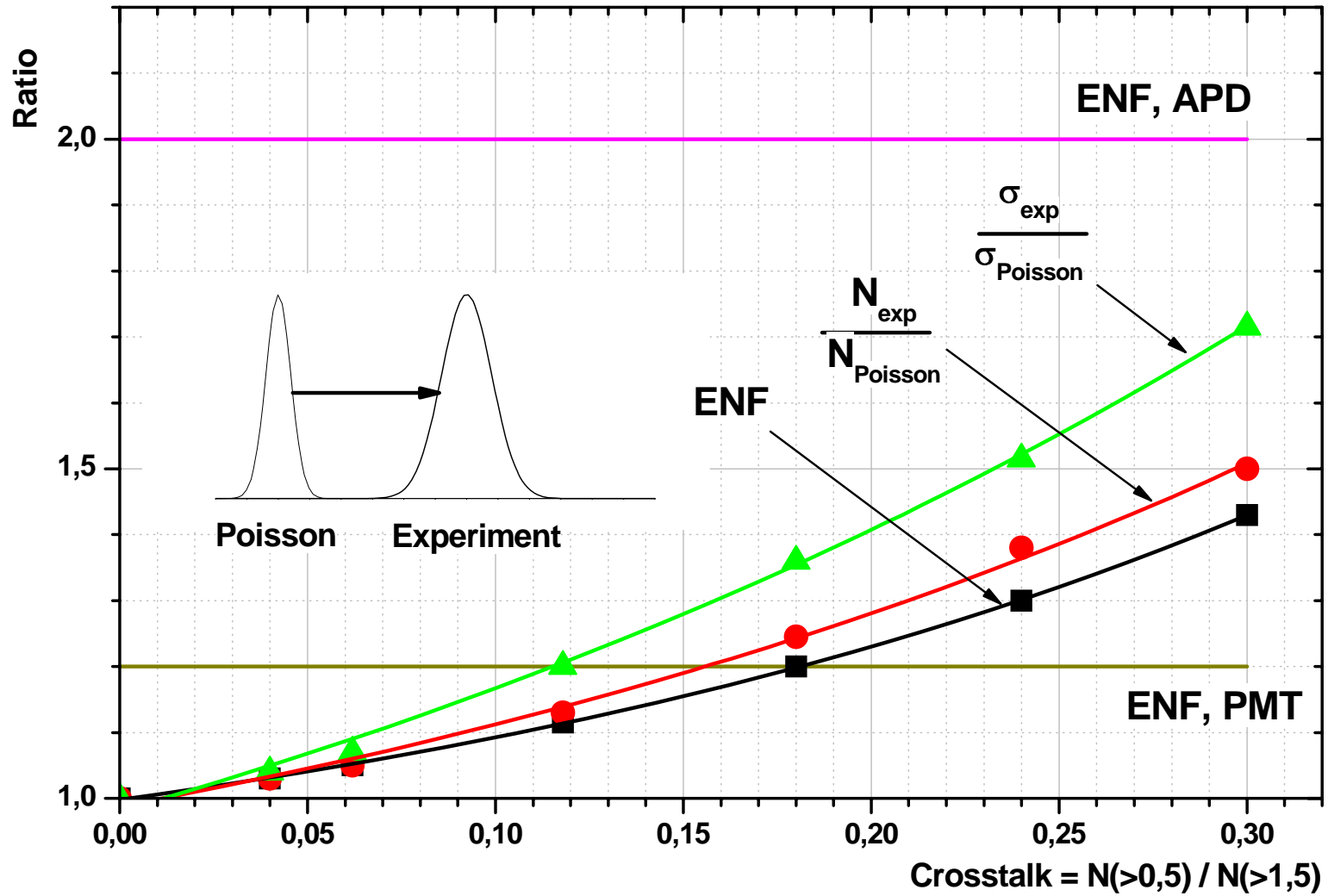
Poisson distribution:

pixel fired/phe= ~1

ENF= ~1

B.Dolgoshein, LIGHT06

14



# The suppression of SiPM noise for as low threshold as possible is extremely important for:

→ Imaging Atmospheric Cherenkov Telescopes (e.g. MAGIC) or space-born fluorescent telescope EUSO

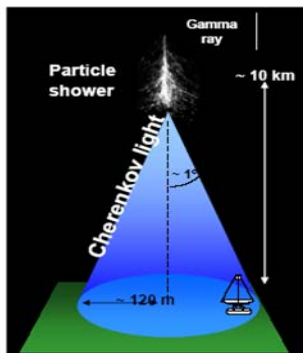
→ threshold  $\sim 1-2$  phe

SiPM for astroparticle Physics

➤ A single photon counting

MAGIC

Major Atmospheric Gamma Imaging Cherenkov Telescope



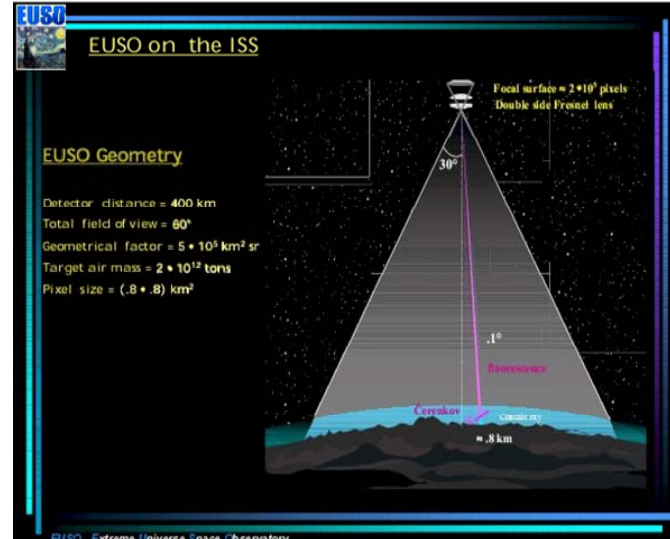
G.Lutz, Conf.on Photodetection, Beaune, June 19-24, 2005

Observation of Cherenkov light from ground based telescope



<http://hegra1.mppmu.mpg.de/MAGICWeb/>

5



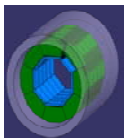
EUSO - Extreme Universe Space Observatory

B.Dolgoshein, SiPM review

33

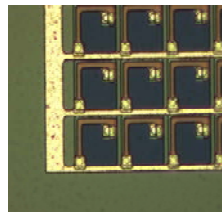
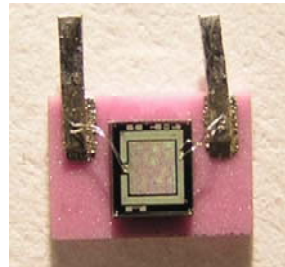
# Another example of low SiPM requirements:

- Scintillation Calorimetry- for instance a SciTile Imagine Hadron Calorimeter for ILC (CALICE Collaboration), sci tile size: a few cm
- Typical threshold is  $\sim 5-7$  phe

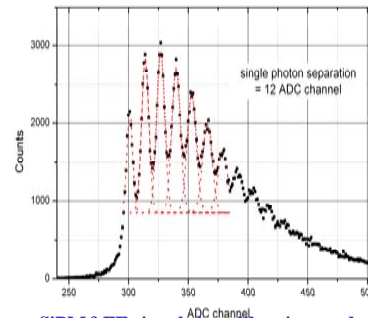


## SiPM tile fibre system

- SiPM developed by MEPhI/PUSAR
  - Gain  $\sim 10^6$ , bias  $\sim 50$  V, size  $1 \text{ mm}^2$ , 1156 pixels
  - Eff (green)  $\sim 15\%$ , quenching R  $\sim 1 - 10 \text{ M}\Omega$
- SiPM tile fibre system integration: ITEP
  - $3 \times 3 \times 0.5 \text{ cm}^3$  tiles from UNIPLAST, Russia
  - WLS fibre Kuraray Y11(300) 1mm
  - Matted edges, 2% light xtalk per edge
  - Faces covered with EM mirror foil



A big 8000 channel HCAL prototype with tail catcher is constructed by CALICE (DESY, ITEP, LAL, MEPhI, NIU, Prague, UK) for analogue and semidigital modes

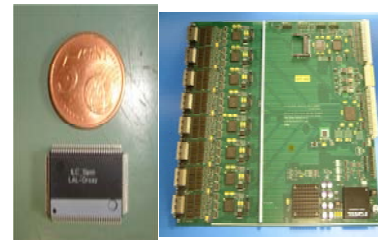


SiPM&FE signals in calibration mode



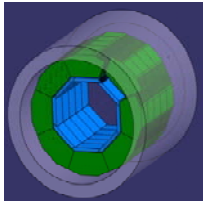
One plane with SiPMs and WLS fibers installed into  $3 \times 3$ ,  $6 \times 6$  and  $12 \times 12 \text{ cm}^2$   $0.5 \text{ cm}$  thick tiles

CERN test beam, 2006

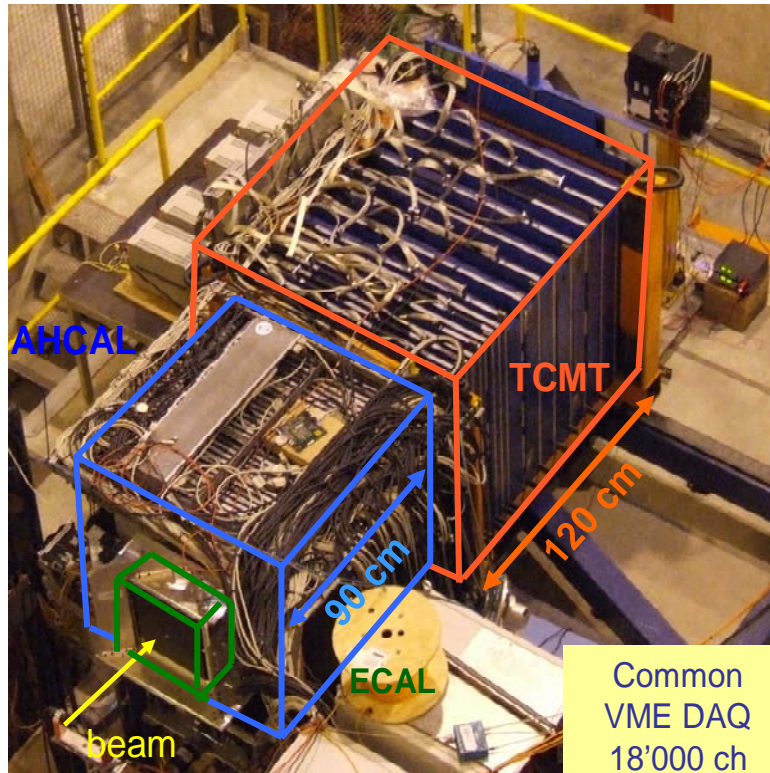


LAL 18 ch. SiPM FE chip

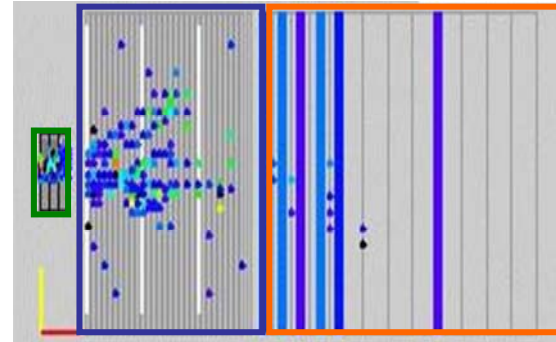




# Test beam installation at CERN SPS



MCPDs for calorimetry



July - Nov. 2006

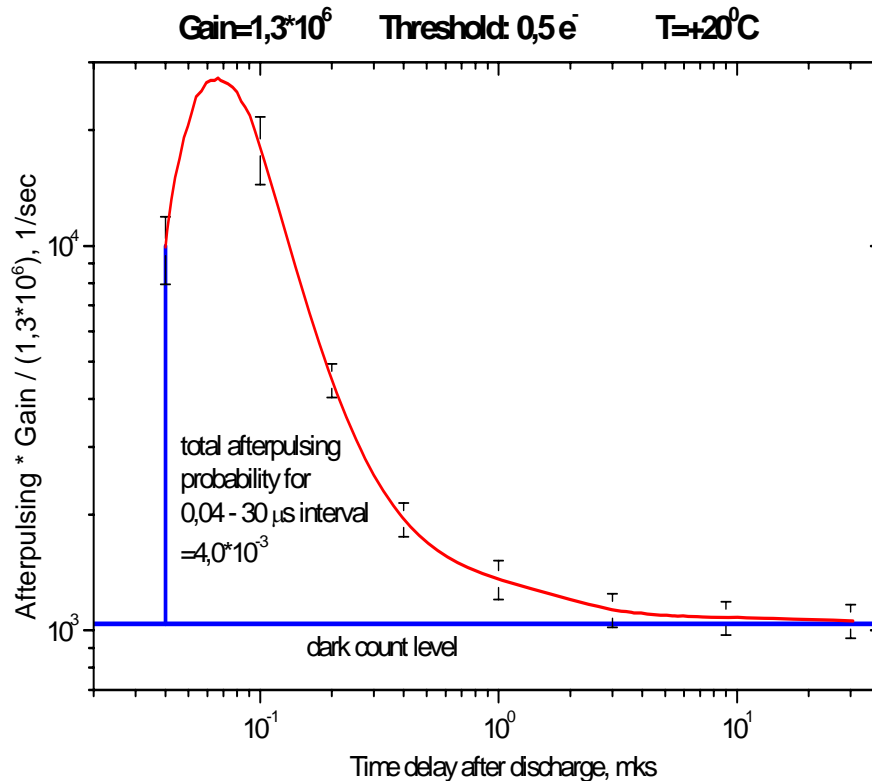
CALICE detectors installed in the H6b experimental hall at the CERN SPS

smooth commissioning, prepared at DESY

Hadron (electron) beam  
6 - 100 (50) GeV

# Afterpulsing AP

→ The lifetimes of trapped electron are mostly rather small:  
less than  $\sim 100$  ns



Therefore a single pixel recovery time  $R_{\text{quench}} \times C_{\text{pixel}}$  should not be not very small and recommended at level of .5-1 mks

→ Even for high Gain  $\times$  PDE the Afterpulsing has to be small enough:  
 $AP(\text{Gain}=10 \cdot 7) \approx \sim 1\%$   
for recovery time of  $> 500$  ns

# Optical Crosstalk OC

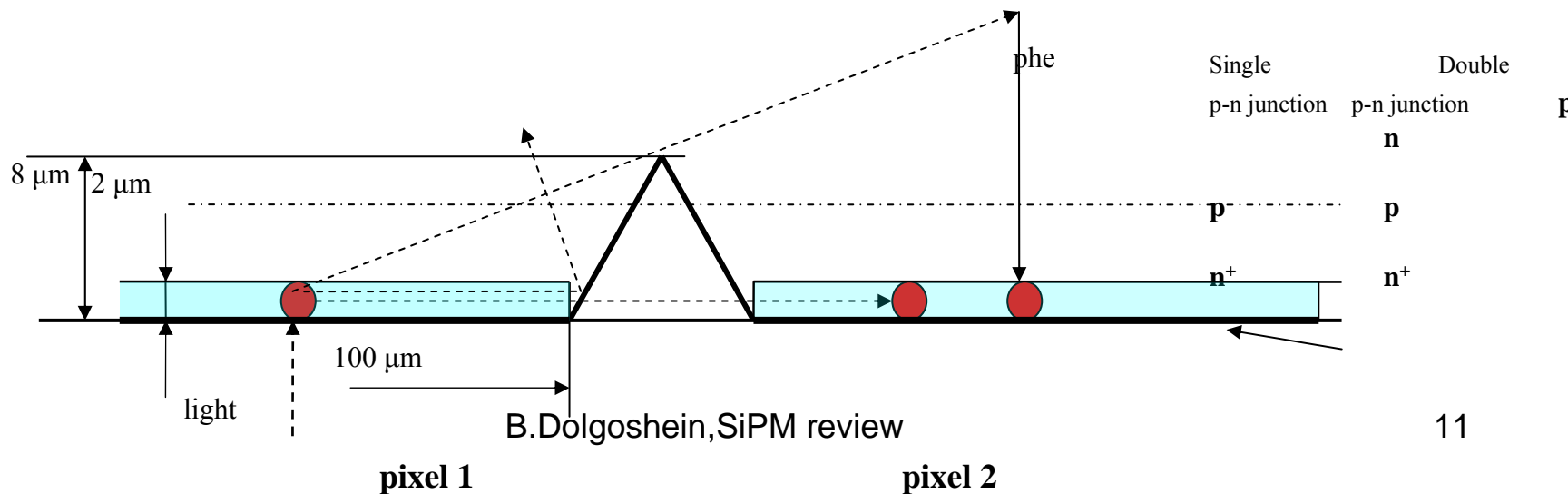
OC has two components

FIRST: phe's are induced in high electric field depletion region of neighbouring pixels

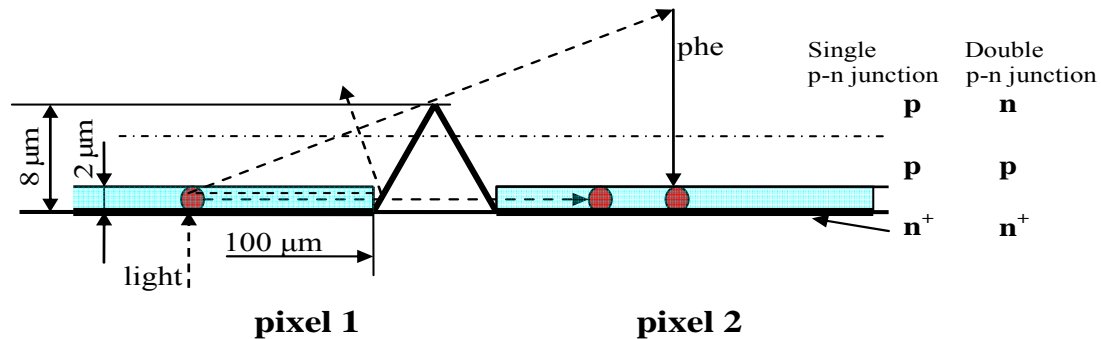
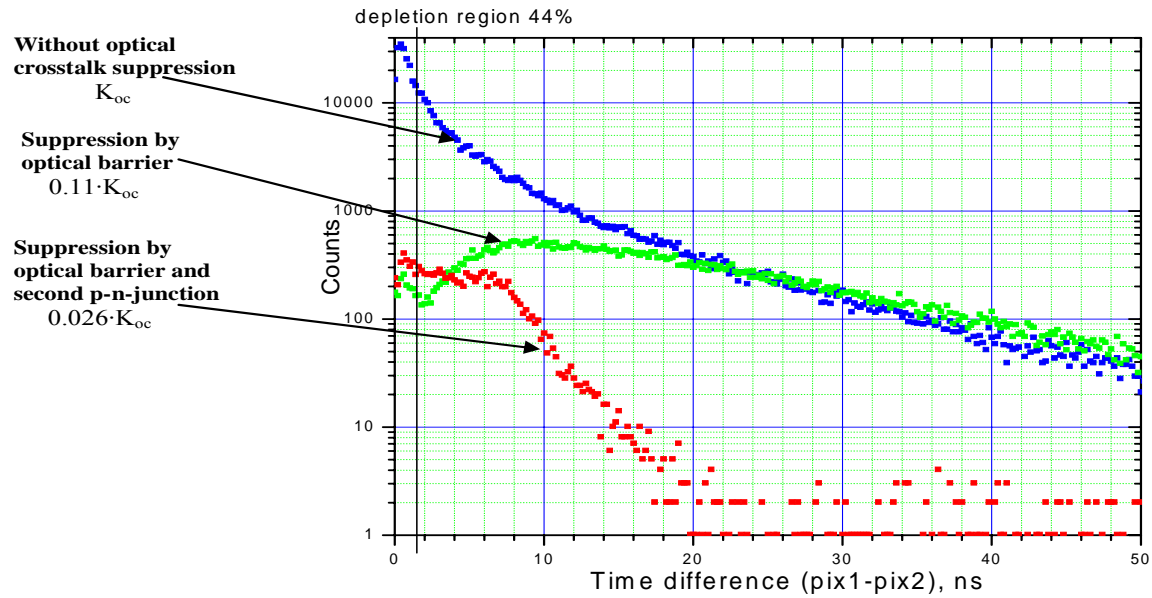
→ this mechanism is very fast:  $\sim 1\text{ns}$  (prompt OC)

SECOND: The same in undepleted region and then the diffusion (or drift) to high electric field Geiger region of neighbouring pixels

→ this process is delayed: later than  $1\text{ns}$



# Optical Crosstalk studies



*Optical crosstalk between two separate pixels*

# Results of Optical Crosstalk studies

two separated pixels  
pixel size 100 $\mu$ m, pitch 130 $\mu$ m  
gain  $2 \times 10^7$   
recovery time  $> 1$  ns  
PDE=35%

## OPTICAL CROSSTALK:

- prompt ( $< \sim 1$  ns, p.e. in depletion region) ~50%
- delayed ( $> \sim 1$  ns) ~50%

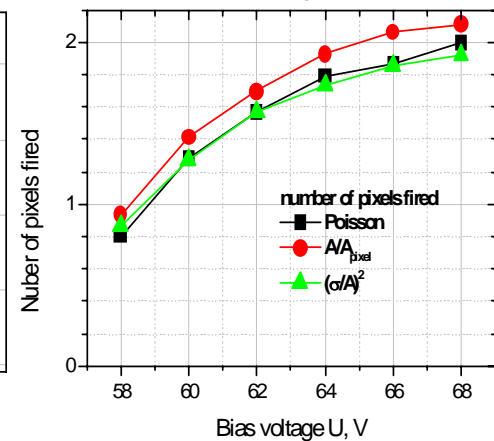
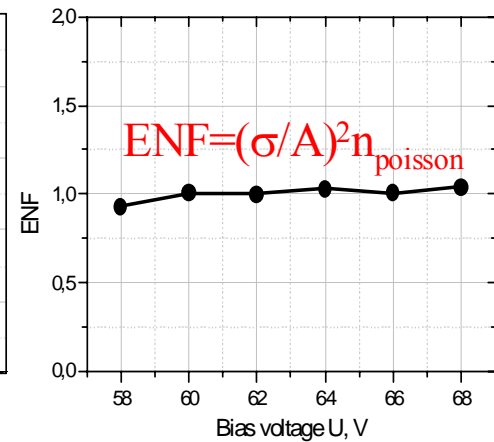
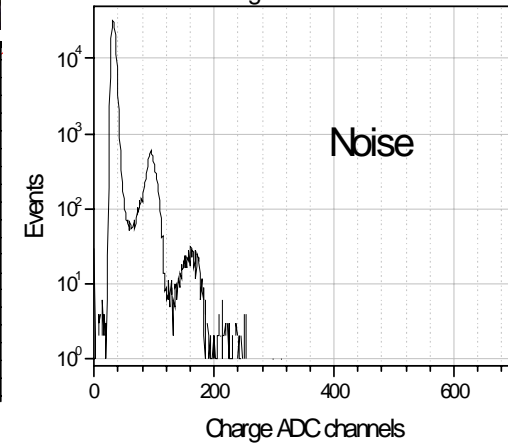
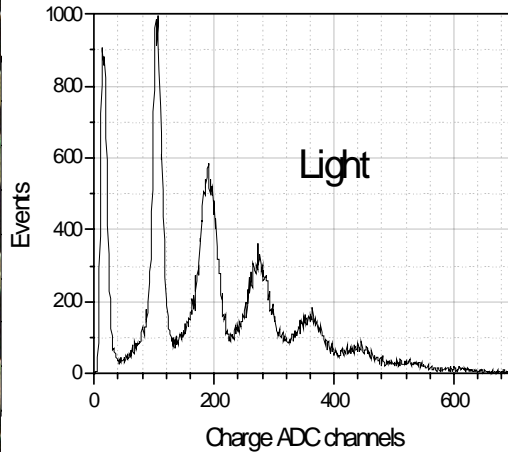
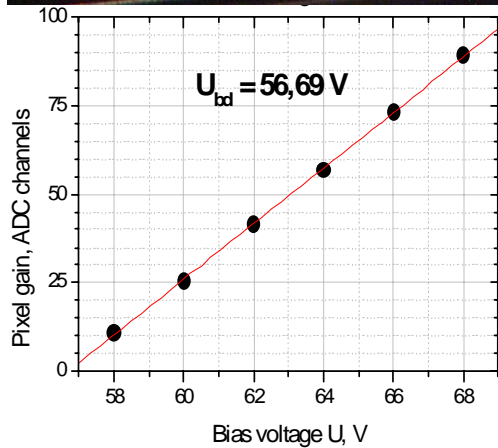
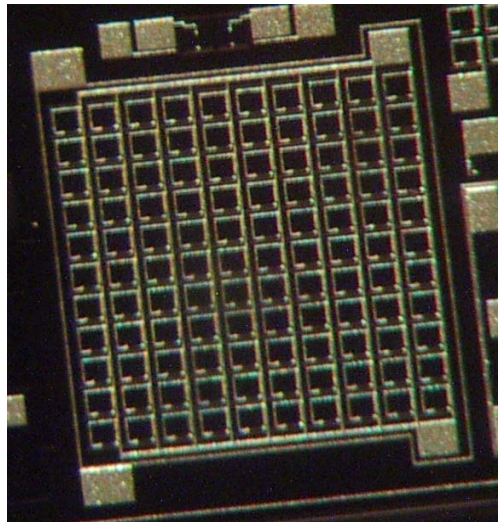
## OPTICAL CROSSTALK

### SUPPRESSION FACTOR:

- with optical barriers (tranches, 8 $\mu$ m deep) ~9
- with optical barriers + second n-p junction ~4.5
- Total: ~40



# First step: SiPM 1.4x1.4 mm<sup>2</sup> with OC suppression topology



# Second step: 5x5mm<sup>2</sup> SiPM with OC and AP suppression

SiPM parameters:

→ size	5x5mm <sup>2</sup>
→ double junction structure with optical barriers 6mkm	
→ number of pixels	1600
→ pixel size	100mkm
→ gain	$2 \times 10^7$
→ geometrical eff.(filling factor)	64%
→ pixel capacitance	~1pF
→ output SiPM capacitance	~160pF
→ antireflection entrance window	
→ single pixel recovery time	~ .5mks



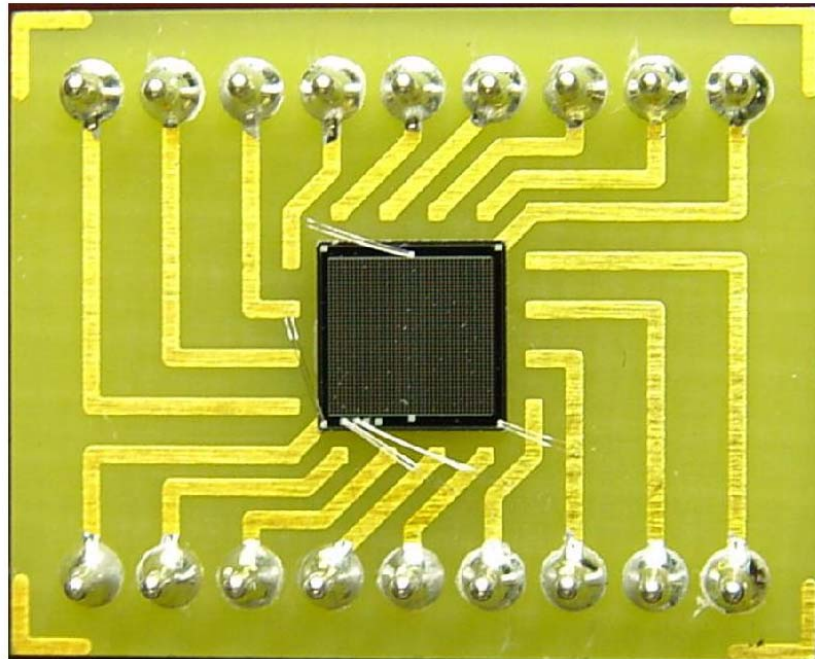


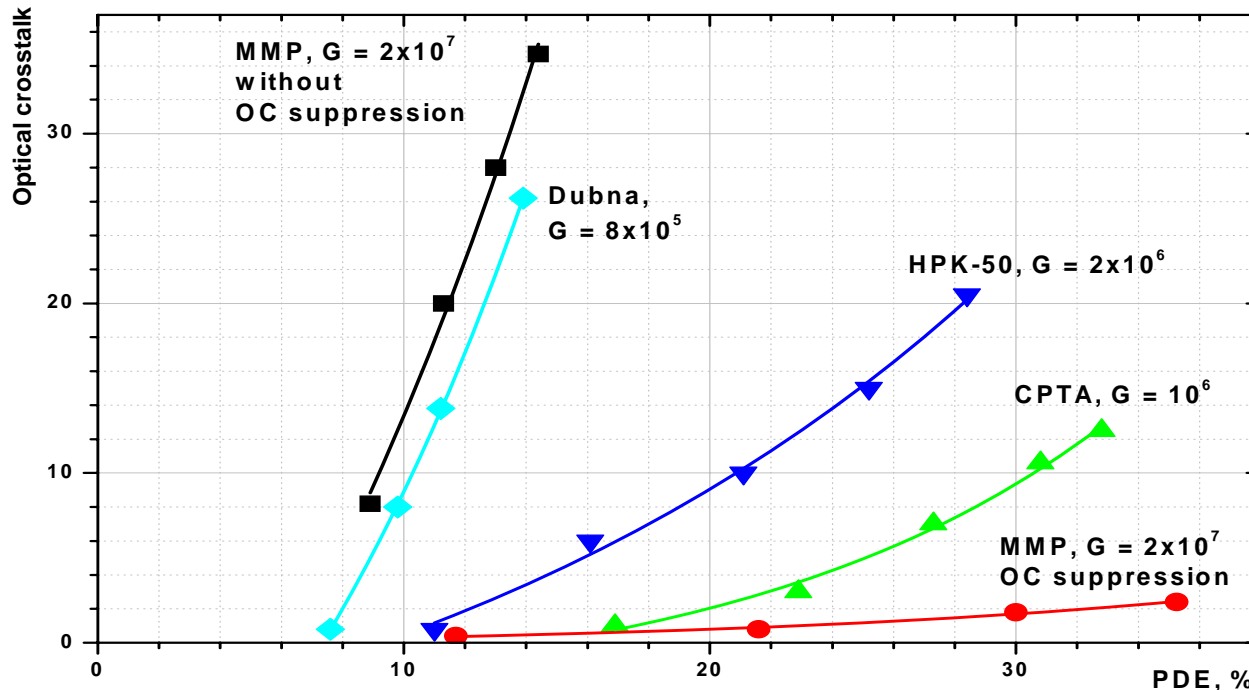
Figure 3:  $25(5 \times 5)mm^2$  SiPM. It consists of the array of 1600( $40 \times 40$ ) micropixels with  $100 \times 100\mu m^2$  size.

# OC and AP suppression for 5x5mm<sup>2</sup> SiPM Comparison with other producers devices

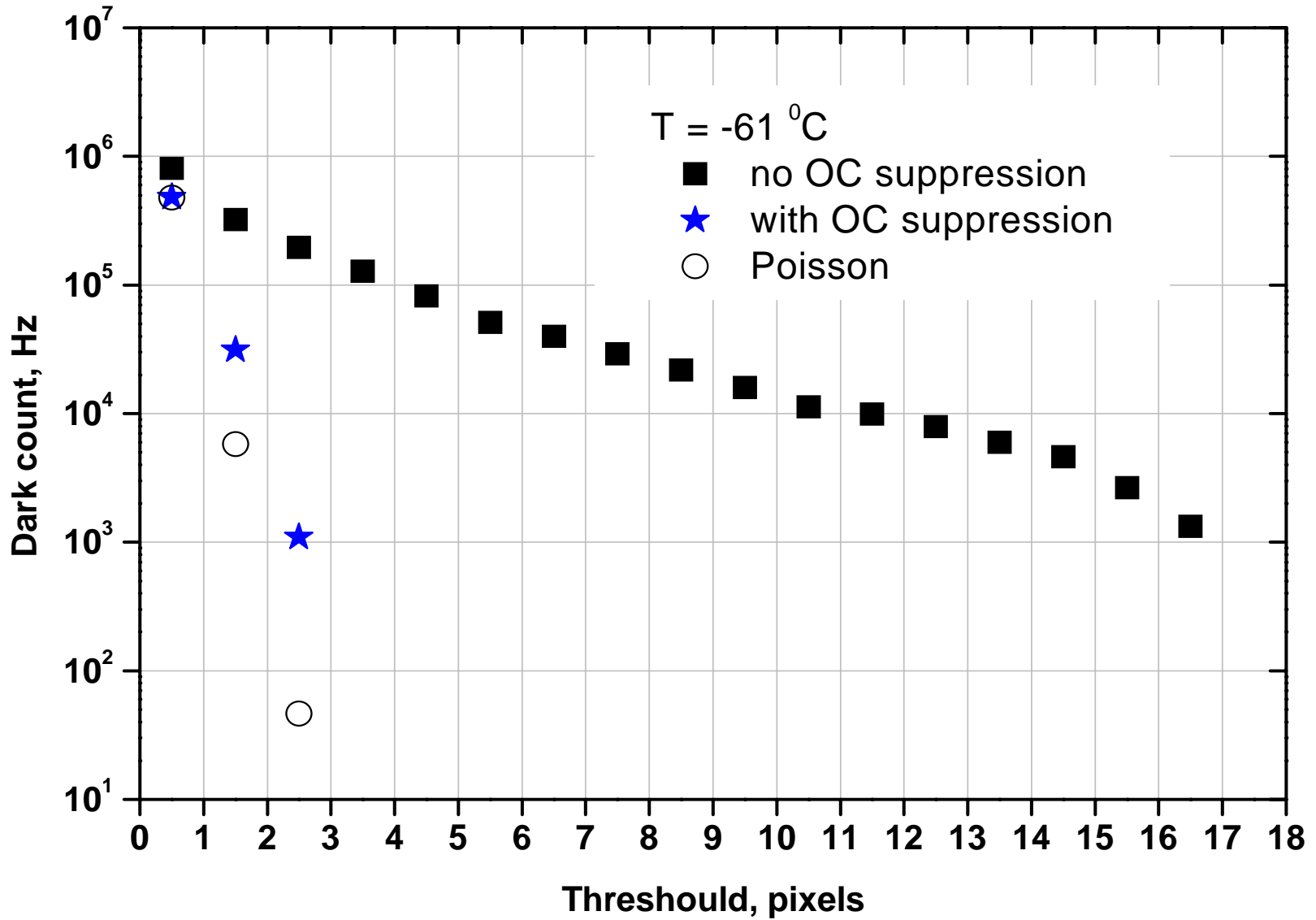
-extracted from measurements made by Yu.Musienko, PD07, Kobe, 2007

→ Let's define the Optical Crosstalk as

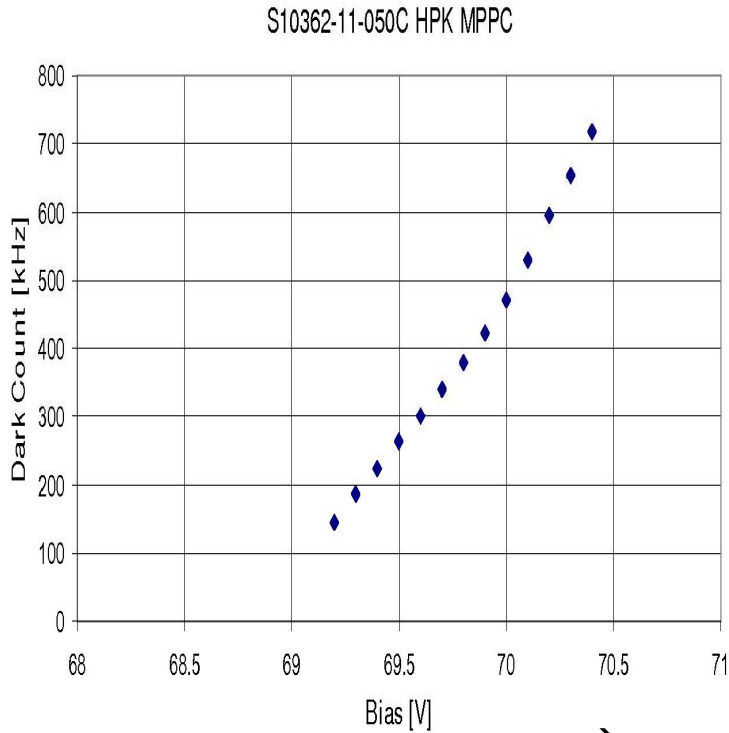
$$OC = N(\text{threshold} > .5 \text{ phe}) / N(\text{threshold} > 1.5 \text{ phe})$$



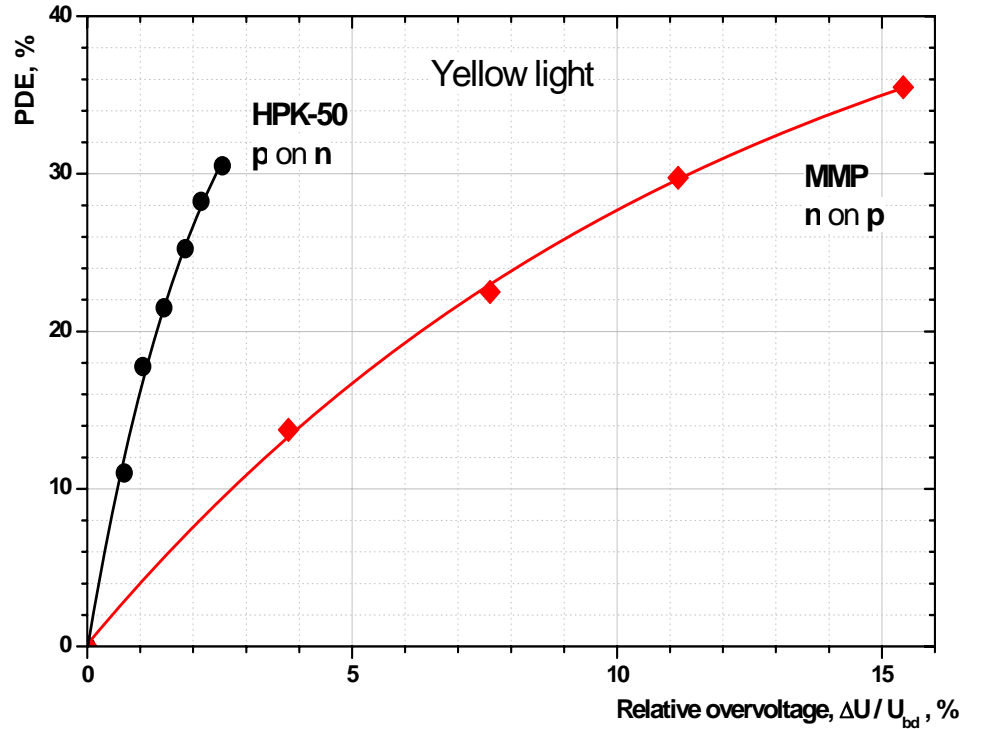
5x5 mm<sup>2</sup> SiPM: OC+AP( RquenchxCpix = .5mks) = ~2.5%,  
for PDE=36%, Gain+2x10\*7



# Comparison the N on P structure(5x5mm<sup>2</sup>) with P on N structure(HPK-50)



←----- Bias [V] ----->  
**Overvoltage ~ 2.5%**



Much lower relative overvoltage for **P** on **N** structure (P entrance window) results much lower Dark Rate (~ order of magnitude less)

HPK-50 MPPC-measured by Yu.Musienko, Kobe, 2007

*Y. Musienko*

# Timing by 5x5mm<sup>2</sup> SiPM: signal shape

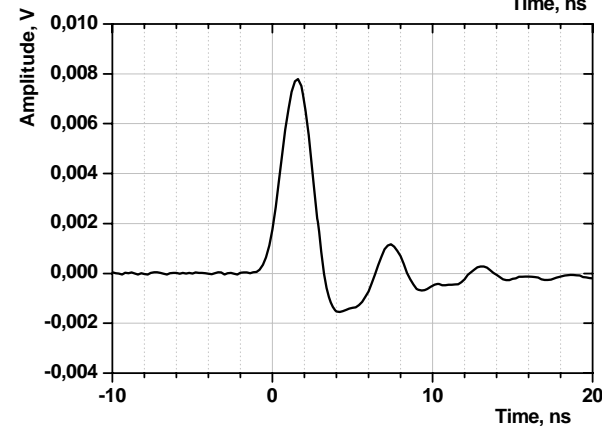
→ Because high SiPM output capacitance (~160pF)

a special FE electronics has been developed:

low input impedance (a few Ohm)  
current amplifier+shaper



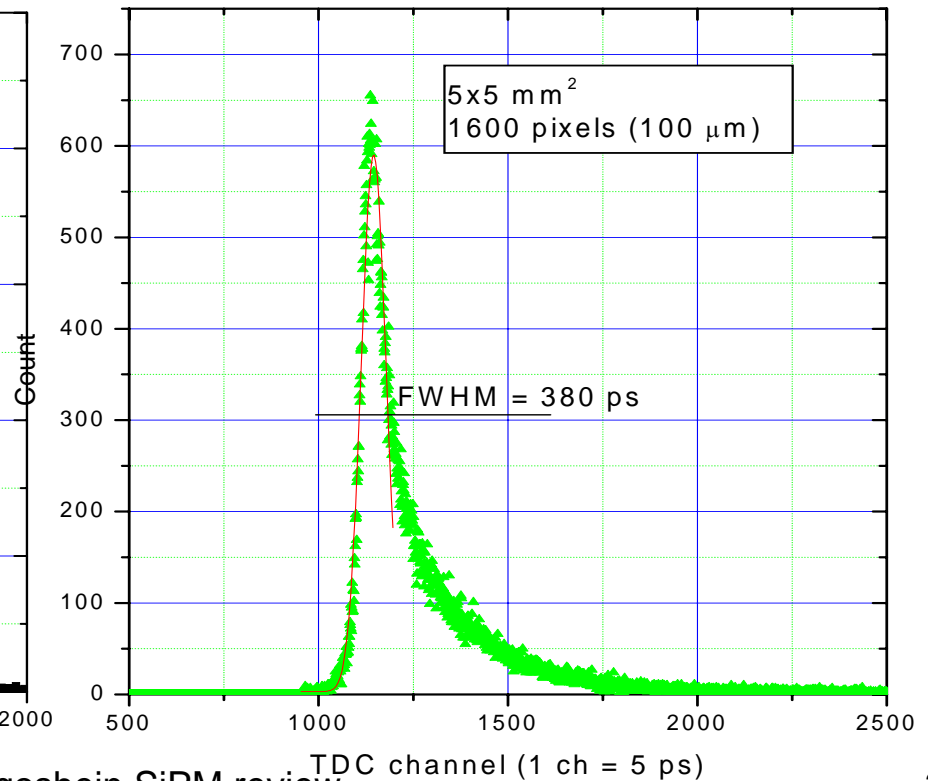
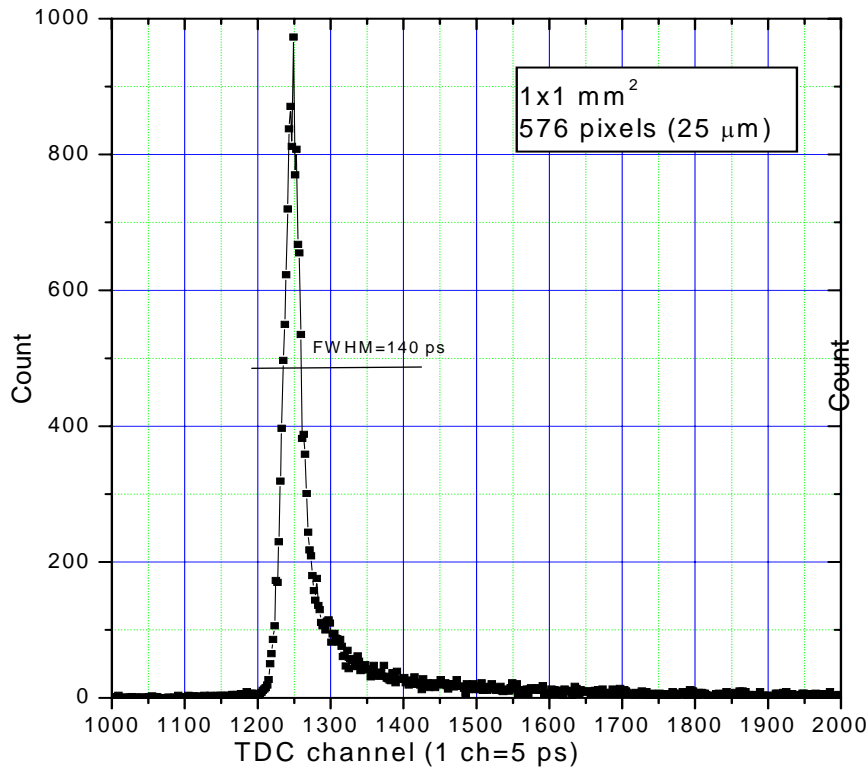
50 Ohm  
FWHM  
15ns



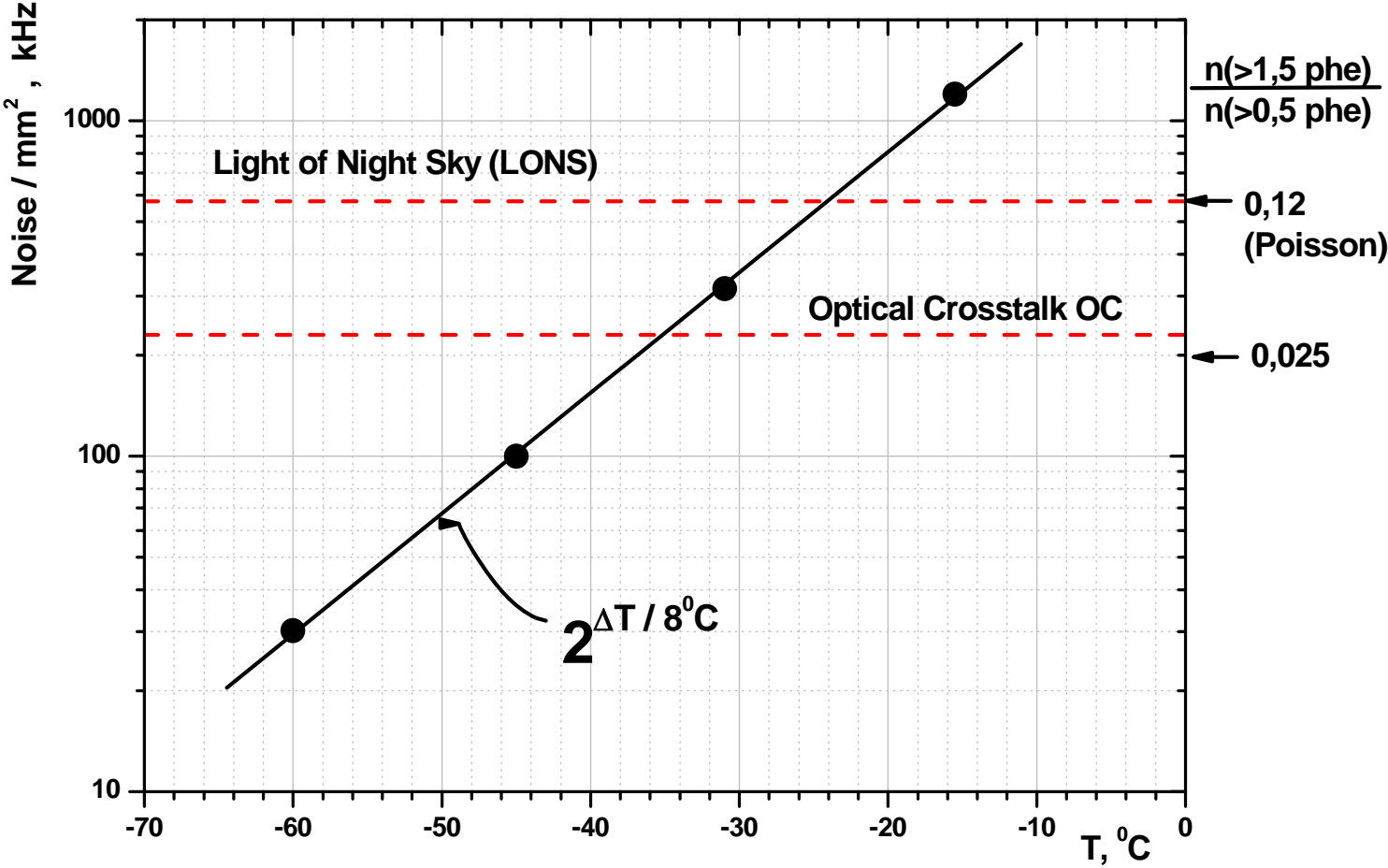
~ 7 Ohm  
+shaper  
FWHM  
2,5ns

# Timing by 5x5mm<sup>2</sup> SiPM: a single phe resolution

Fig.'s below show the impact of SiPM size(size of one pixel and SiPM itself)on single phe resolution **FWHM** for SiPMs 1x1mm<sup>2</sup>(pixel size 25mkm) and 5x5mm<sup>2</sup>(pixel size 100mkm)

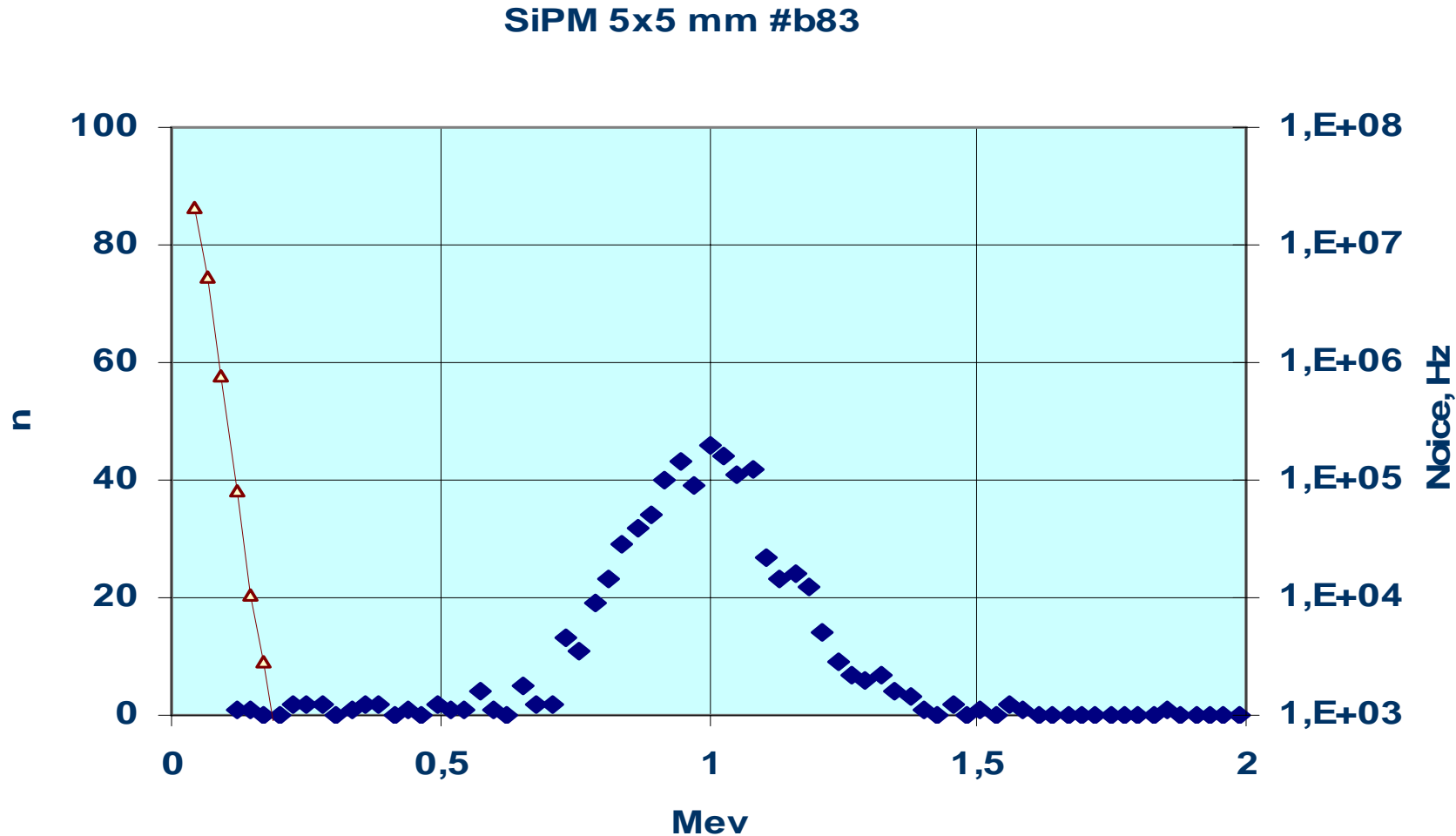


# Dark Rate vs temperature → acceptable temperature



# 5x5 mm<sup>2</sup> SiPM with OC suppression: performance at room temperature

→ SiPM directly coupled with 5x5 mm<sup>2</sup> plastic scintillator rod + Sr90 beta-source





# CONCLUSIONS

- **5x5mm<sup>2</sup> SiPM with suppression of (OC + AP) down to 2-3% has been developed , produced and tested**
- **Excess Noise Factor measured is quite low (~2%)**
- **Special FE electronics for fast timing has been developed and tested**
  - significant improvement of trigger conditions for Imaging Cherenkov and fluorescent Telescopes and Sci systems
- **Such a SiPM met the main requirements for MAGIC telescope except:**
  - PDE should be improved especially for UV
  - increase of filling factor, more thin entrance window
  - Dark rate still too large, cooling system is needed
  - transition from N on P to P on N structure like MPPC